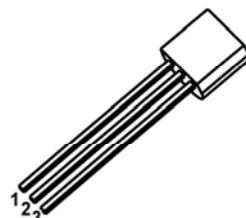
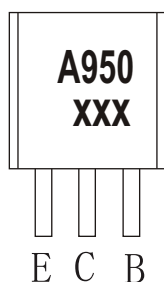


**TO-92 Plastic-Encapsulate Transistors****2SA950** TRANSISTOR (PNP)**FEATURES**

- 1W Output Applications
- Complementary to 2SC2120

TO-92

1. EMITTER
2. COLLECTOR
3. BASE

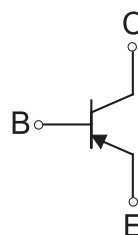
**MARKING**

A950=Device code

XXX=Code

GXX=Green molding compound device

CXX=Normal molding compound device

Equivalent Circuit**ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
2SA950	TO-92	Bulk	1000pcs/Bag
2SA950-TA	"O-92	"ape	2000pcs/Box

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-35	V
V _{CEO}	Collector-Emitter Voltage	-30	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current -Continuous	-0.8	A
P _D	Collector Power Dissipation	600	mW
R _{KJA}	Thermal Resistance from Junction to Ambient	208	°C /W
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

ELECTRICAL CHARACTERISTICS

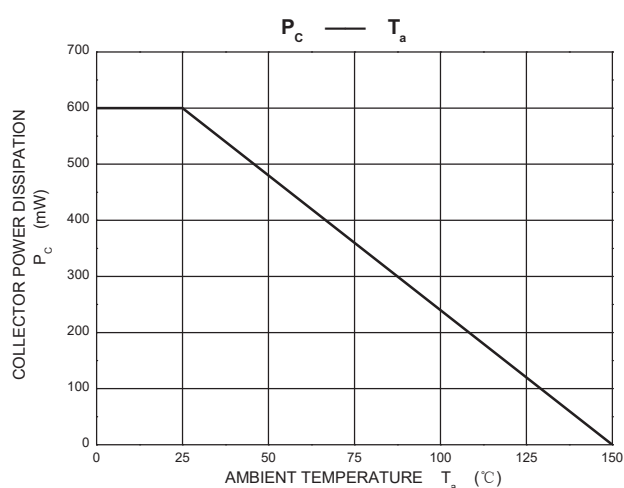
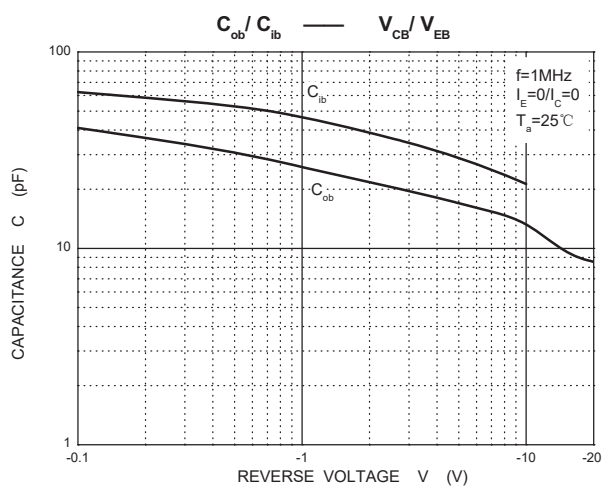
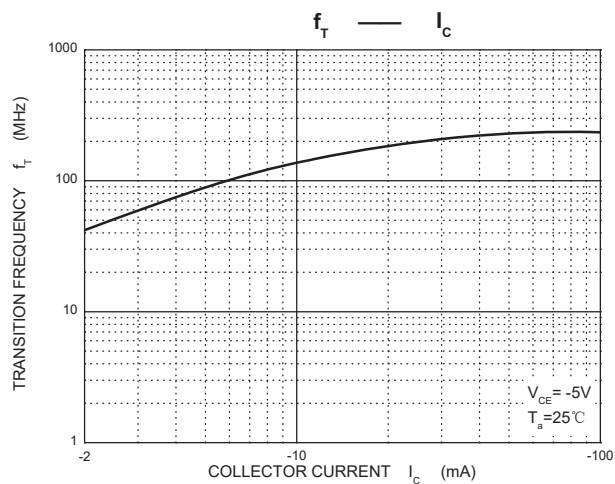
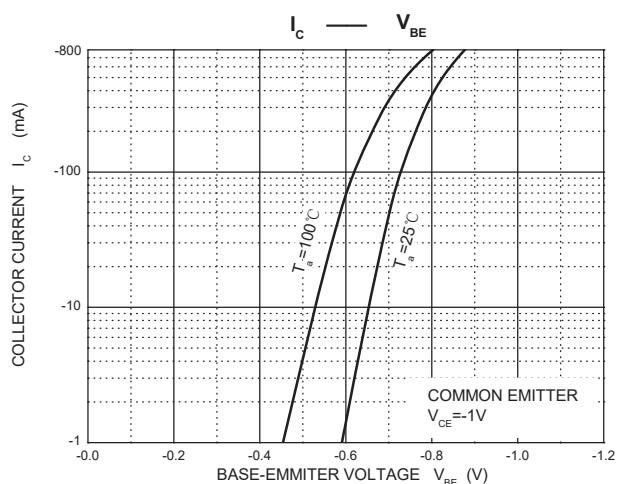
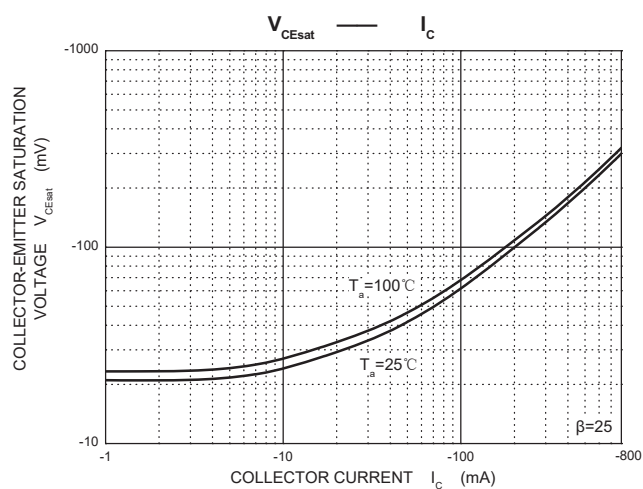
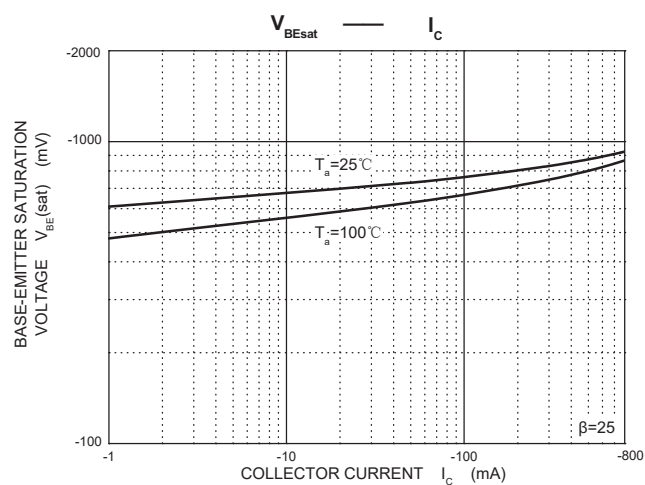
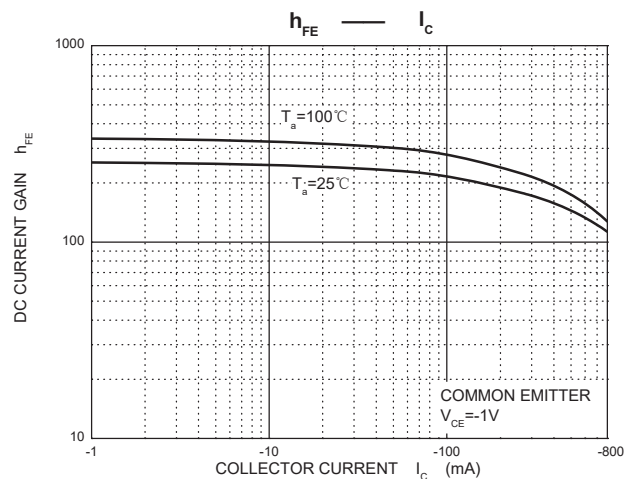
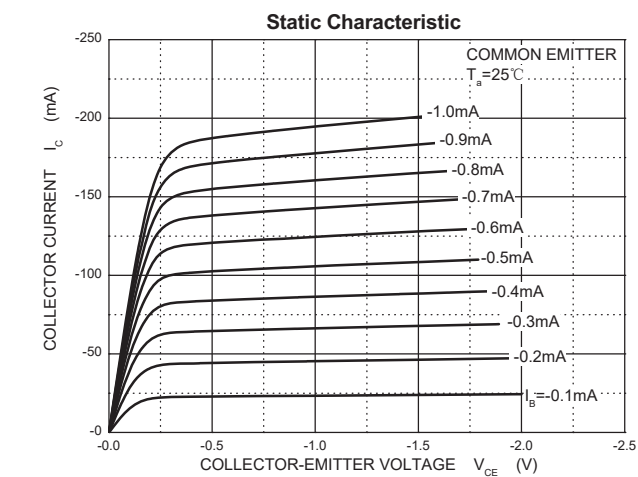
$T_a=25^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	M&+	T0!	Max	U+&'
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -0.1\text{mA}$, $I_E = 0$	-35			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}$, $I_B = 0$	-30			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -0.1\text{mA}$, $I_C = 0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB} = -35\text{V}$, $I_E = 0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{V}$, $I_C = 0$			-0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE} = -1\text{V}$, $I_C = -100\text{mA}$	100		320	
	$h_{FE(2)}$	$V_{CE} = -1\text{V}$, $I_C = -700\text{mA}$	35			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -500\text{mA}$, $I_B = -20\text{mA}$			-0.7	V
Emitter-base voltage	V_{BE}	$V_{CE} = -1\text{V}$, $I_C = -10\text{mA}$	-0.5		-0.8	V
Collector Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}$, $I_E = 0$ $f = 1\text{MHz}$		19		pF
Transition frequency	f_T	$V_{CE} = -5\text{V}$, $I_C = -10\text{mA}$		120		MHz

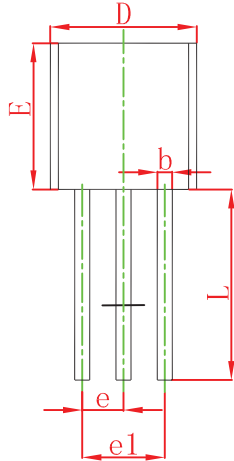
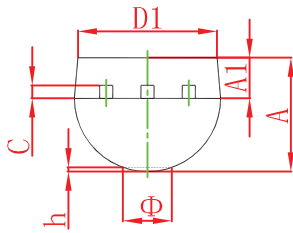
CLASSIFICATION OF $h_{FE(1)}$

Rank	O	Y
Range	100-200	160-320

Typical Characteristics

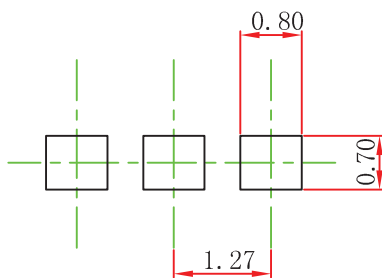


TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
v		1.600		0.063
h	0.000	0.380	0.000	0.015

TO-92 Suggested Pad Layout



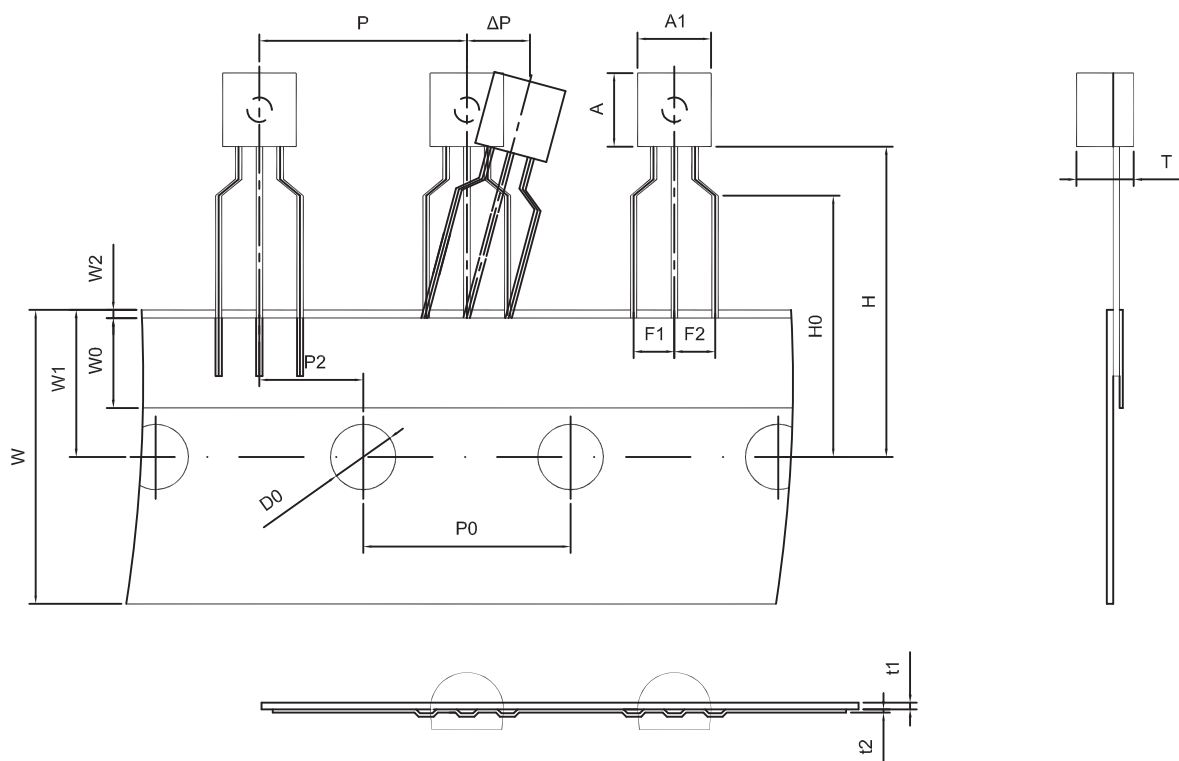
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

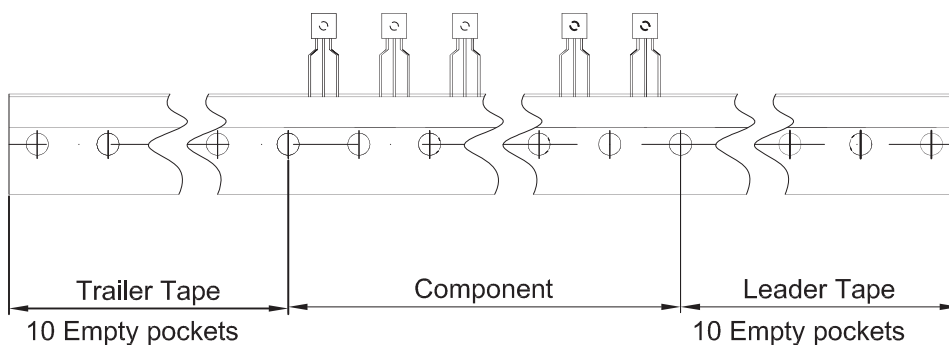
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TO-92 Tape and Reel



Dimiensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250